

HD74LV1GW57A

Configurable Multiple–Function Gate

REJ03D0081-0200 Rev.2.00 May 19, 2006

Description

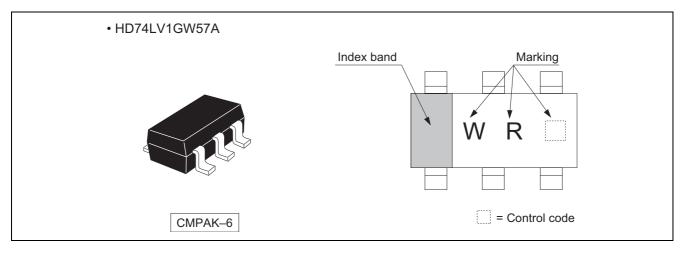
The HD74LV1GW57A has configurable multiple–function gate in a 6 pin package. The Output state is determined by eight patterns of 3–bit input. The user can choose the logic functions AND, NAND, NOR, EX–NOR. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.65 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V) All outputs V_O (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current $\pm 6 \text{ mA}$ (@V_{CC} = 3.0 V to 3.6 V), $\pm 12 \text{ mA}$ (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

| Part Name | Package Type | Package Code (Previous Code) | Package Abbreviation | Taping Abbreviation (Quantity) |
|-----------------|--------------|---------------------------------|-------------------------|-----------------------------------|
| HD74LV1GW57ACME | CMPAK-6 pin | PTSP0006JA-A (CMPAK-6V) | СМ | E (3,000 pcs / Reel) |

Outline and Article Indication





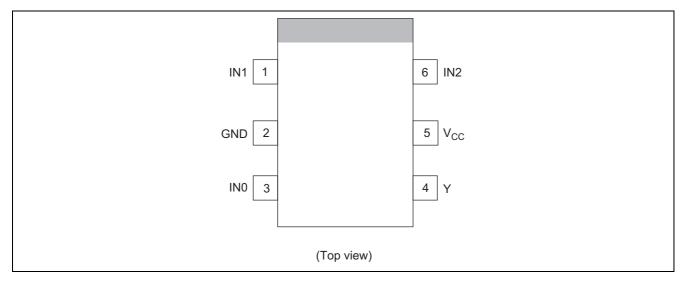
Function Table

| | Inputs | | | | | | | | |
|-----|--------|-----|---|--|--|--|--|--|--|
| IN2 | IN1 | INO | Y | | | | | | |
| L | L | L | н | | | | | | |
| L | L | Н | L | | | | | | |
| L | Н | L | н | | | | | | |
| L | Н | Н | L | | | | | | |
| Н | L | L | L | | | | | | |
| Н | L | Н | L | | | | | | |
| Н | Н | L | Н | | | | | | |
| Н | Н | Н | Н | | | | | | |

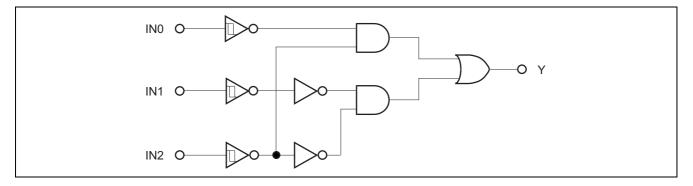
H : High level

L : Low level

Pin Arrangement



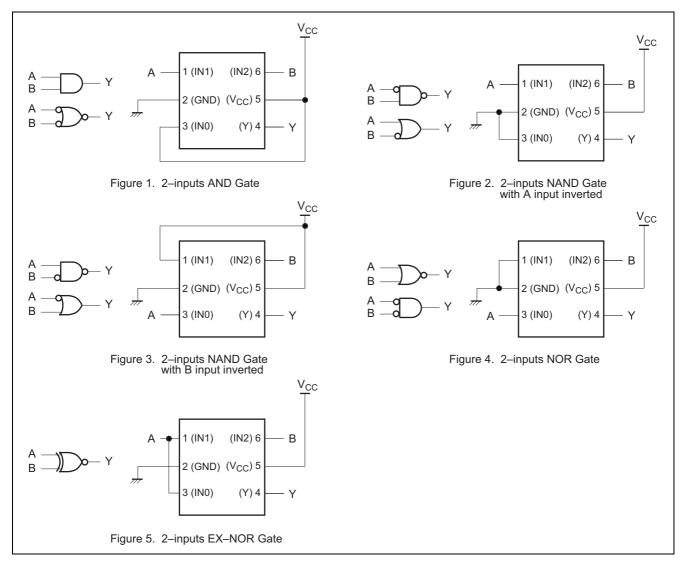
Logic Diagram



Function Selection Table

| Logic Function | Figure No. | | | | | |
|---------------------------------------|------------|--|--|--|--|--|
| 2–input AND | 1 | | | | | |
| 2-input AND with both inputs inverted | 4 | | | | | |
| 2-input NAND with one input inverted | 2, 3 | | | | | |
| 2-input OR with one input inverted | 2, 3 | | | | | |
| 2-input NOR | 4 | | | | | |
| 2-input NOR with both inputs inverted | 1 | | | | | |
| 2-input EX-NOR | 5 | | | | | |

Logic Configurations





Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Test Conditions |
|---|-------------------------------------|-------------------------------|------|------------------------------------|
| Supply voltage range | V _{CC} | -0.5 to 7.0 | V | |
| Input voltage range *1 | VI | -0.5 to 7.0 | V | |
| Output voltage range *1, 2 | V | –0.5 to V _{CC} + 0.5 | V | Output : H or L |
| Output voltage range | Vo | -0.5 to 7.0 | V | V _{CC} : OFF |
| Input clamp current | I _{IK} | -20 | mA | V ₁ < 0 |
| Output clamp current | I _{ОК} | ±50 | mA | $V_0 < 0 \text{ or } V_0 > V_{CC}$ |
| Continuous output current | Ι _Ο | ±25 | mA | $V_{O} = 0$ to V_{CC} |
| Continuous current through V _{CC} or GND | I _{CC} or I _{GND} | ±50 | mA | |
| Maximum power dissipation at Ta = 25° C (in still air) ^{*3} | P _T | 200 | mW | |
| Storage temperature | Tstg | -65 to 150 | °C | |

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

| ltem | Symbol | Min | Max | Unit | Conditions |
|------------------------------------|-----------------------|------|-----------------|---------|----------------------------------|
| Supply voltage range | V _{CC} | 1.65 | 5.5 | V | |
| Input voltage range | VI | 0 | 5.5 | V | |
| Output voltage range | Vo | 0 | V _{CC} | V | |
| | | _ | 1 | | V _{CC} = 1.65 to 1.95 V |
| | | _ | 2 | | V_{CC} = 2.3 to 2.7 V |
| | IoL | _ | 6 | | V_{CC} = 3.0 to 3.6 V |
| Output ourroat | | _ | 12 | - mA | V_{CC} = 4.5 to 5.5 V |
| Output current | Іон | _ | -1 | | V _{CC} = 1.65 to 1.95 V |
| | | _ | -2 | | V_{CC} = 2.3 to 2.7 V |
| | | _ | -6 | | V_{CC} = 3.0 to 3.6 V |
| | | _ | -12 | | V_{CC} = 4.5 to 5.5 V |
| | | 0 | 300 | | V _{CC} = 1.65 to 1.95 V |
| anut transition rise or fall rate | A. + / A. | 0 | 200 | na / \/ | V_{CC} = 2.3 to 2.7 V |
| Input transition rise or fall rate | $\Delta t / \Delta v$ | 0 | 100 | ns / V | V_{CC} = 3.0 to 3.6 V |
| | | 0 | 20 | 7 | V_{CC} = 4.5 to 5.5 V |
| Operating free-air temperature | Ta | -40 | 85 | °C | |

Note: Unused or floating inputs must be held high or low.



Electrical Characteristic

Ta = -40 to $85^{\circ}C$

| Item | Symbol | V _{cc} (V) * | Min | Тур | Max | Unit | Test condition |
|-----------------------------|-----------------------------|-----------------------|-----------------------|-----|-----------------------|------|---|
| | | 1.65 to 1.95 | _ | | V _{CC} ×0.75 | | |
| | | 2.5 | _ | | 1.75 | | |
| | V _T ⁺ | 3.3 | _ | | 2.31 | | |
| | | 5.0 | _ | | 3.50 | | |
| | | 1.65 to 1.95 | V _{CC} ×0.25 | _ | _ | | |
| Threshold | v | 2.5 | 0.75 | _ | _ | v | |
| voltage | V _T ⁻ | 3.3 | 0.99 | _ | _ | V | |
| | | 5.0 | 1.5 | _ | _ | | |
| | | 1.65 to 1.95 | 0.1 | _ | V _{CC} ×0.4 | | |
| | A) (| 2.5 | 0.25 | _ | 1.0 | | |
| | ΔV_T | 3.3 | 0.33 | | 1.32 | | |
| | | 5.0 | 0.5 | | 2.0 | | |
| | | Min to Max | V _{cc} -0.1 | _ | — | | I _{OH} = –50 µА |
| | | 1.65 | 1.4 | _ | — | - | I _{OH} = -1 mA |
| | V _{OH} | 2.3 | 2.0 | — | — | | $I_{OH} = -2 \text{ mA}$ |
| | | 3.0 | 2.48 | — | — | | I _{OH} = -6 mA |
| Output voltage | | 4.5 | 3.8 | — | — | V | I _{OH} = -12 mA |
| Oulput vollage | | Min to Max | — | _ | 0.1 | v | I _{OL} = 50 μA |
| | | 1.65 | — | _ | 0.3 | | $I_{OL} = 1 \text{ mA}$ |
| | V _{OL} | 2.3 | — | _ | 0.4 | | $I_{OL} = 2 \text{ mA}$ |
| | | 3.0 | — | _ | 0.44 | | $I_{OL} = 6 \text{ mA}$ |
| | | 4.5 | | — | 0.55 | | I _{OL} = 12 mA |
| Input current | l _{iN} | 0 to 5.5 | — | _ | ±1 | μA | $V_{IN} = 5.5 \text{ V or GND}$ |
| Quiescent supply current | Icc | 5.5 | _ | _ | 10 | μA | $V_{IN} = V_{CC} \text{ or } GND,$ $I_O = 0$ |
| Output leakage current | I _{OFF} | 0 | _ | | 5 | μA | $V_{\rm IN}$ or $V_{\rm O} = 0$ to 5.5 V |
| Input capacitance | CIN | 3.3 | _ | 3.0 | | pF | V _{IN} = V _{CC} or GND |

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.



Switching Characteristics

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$

| ltom | Symbol | | Ta = 25°C | | Ta = -40 | to 85°C | l lmit | Test | FROM | то |
|-------------|------------------|-----|-----------|------|----------|---------|--------|------------------------|---------|----------|
| Item | Symbol | Min | Тур | Max | Min | Max | Unit | Conditions | (Input) | (Output) |
| Propagation | t _{PLH} | _ | 15.8 | 29.4 | 1.0 | 33.0 | 20 | C _L = 15 pF | IN | v |
| delay time | t _{PHL} | _ | 22.6 | 40.9 | 1.0 | 45.0 | ns | C _L = 50 pF | IIN | T |

 $V_{CC} = 2.5 \pm 0.2 V$

| Item | Symbol | | Ta = 25°C | | Ta = -40 |) to 85°C | Unit | Test | FROM | то |
|-------------|------------------|-----|-----------|------|----------|-----------|------|------------------------|---------|----------|
| item | Symbol | Min | Тур | Max | Min | Max | Unit | Conditions | (Input) | (Output) |
| Propagation | t _{PLH} | _ | 9.4 | 17.6 | 1.0 | 21.0 | 20 | C _L = 15 pF | IN | V |
| delay time | t _{PHL} | _ | 12.6 | 22.6 | 1.0 | 26.5 | ns | C _L = 50 pF | IIN | I I |

 $V_{CC} = 3.3 \pm 0.3 V$

| ltem | Symbol | | Ta = 25°C | | Ta = -40 |) to 85°C | Unit | Test | FROM | то |
|-------------|------------------|-----|-----------|------|----------|-----------|------|-----------------------|---------|----------|
| nem | Symbol | Min | Тур | Max | Min | Max | Unit | Conditions | (Input) | (Output) |
| Propagation | t _{PLH} | — | 7.0 | 11.0 | 1.0 | 13.0 | ns | $C_L = 15 \text{ pF}$ | IN | Y |
| delay time | t _{PHL} | _ | 9.5 | 14.5 | 1.0 | 16.5 | - | $C_L = 50 \text{ pF}$ | | |

 $V_{CC} = 5.0 \pm 0.5 V$

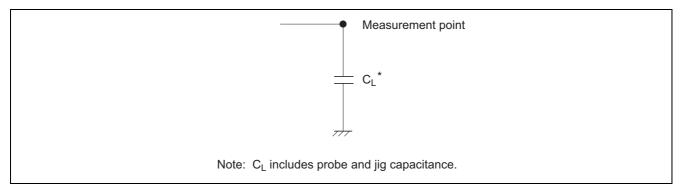
| ltem | Symbol | | Ta = 25°C | | Ta = -40 |) to 85°C | Unit | Test | FROM | то |
|-------------|------------------|-----|-----------|-----|----------|-----------|------|------------------------|---------|----------|
| nem | Symbol | Min | Тур | Max | Min | Max | Unit | Conditions | (Input) | (Output) |
| Propagation | t _{PLH} | | 4.8 | 6.8 | 1.0 | 8.0 | 200 | C _L = 15 pF | IN | Y |
| delay time | t _{PHL} | _ | 6.3 | 8.8 | 1.0 | 10.0 | ns | C _L = 50 pF | IIN | |

Operating Characteristics

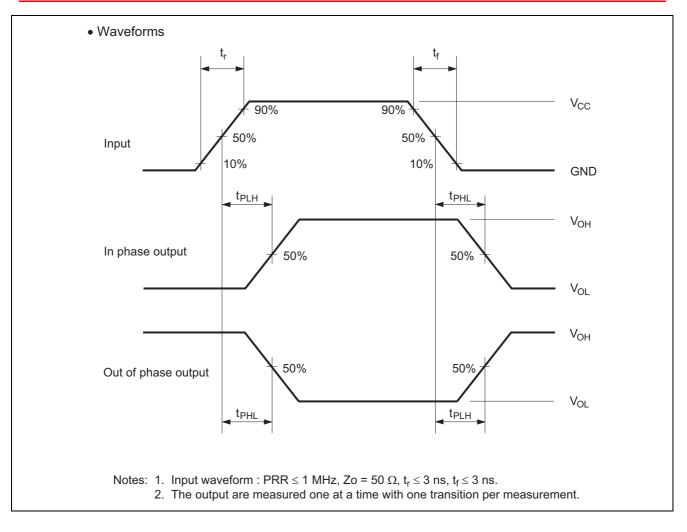
 $C_L = 50 \text{ pF}$

| ltem | Symbol | V _{cc} (V) | | Ta = 25°C | | Unit | Test Conditions | |
|-------------------|----------|---------------------|-----|-----------|-----|------|-----------------|--|
| nem | Symbol | VCC (V) | Min | Тур | Max | Unit | Test conditions | |
| Power dissipation | C | 3.3 | — | 8.5 | — | ρF | f = 10 MHz | |
| capacitance | CPD | 5.0 | | 10.0 | _ | рг | | |

Test Circuit

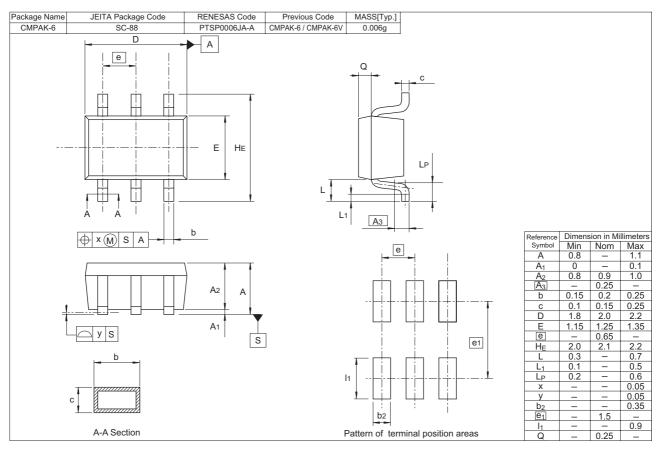








Package Dimensions





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Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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